

#### **General Description**

The AP3041 is a current mode high voltage low-side channel MOSFET controller, which is ideal for boost regulators. It contains all the features needed to implement single-ended primary topology DC/DC converters.

The input voltage of AP3041 ranges from 5V to 27V. Its operation frequency is adjustable from 100kHz to 1MHz.

The AP3041 has UVLO (Under Voltage Lock Out) circuit. It uses two external resistors to set the UVLO voltage. The AP3041 also has an over output voltage protection to limit the output voltage. The OVP voltage can be set through external resistors. If the output voltage is higher than the OVP high threshold point, it will disable the driver and the system is latched up. The output short circuit protection as well as LED low side short to ground detection function can be applied in system.

The AP3041 has other protection functions, such as LED short protection, LED high side short to ground protection, diode short protection, over current protection, over temperature protection and so on.

The AP3041 is available in SOIC-16 package.

#### Features

- Input Voltage Range: 5V to 27V
- 1A Peak and 10V MOSFET Gate Driver
- 20ns Quick MOSFET Gate Driver
- Duty Cycle Limit of 90%
- Programmable UVLO
- PWM Dimming Control
- Programmable Over Voltage Protection
- LED Open Protection
- LED Short Circuit Protection
- Diode Short Circuit Protection
- Output Short Circuit Protection
- LED Low-side Short to Ground Detection
- OV Pin Under Voltage Protection
- Over Current Protection
- Programmable Slope Compensation
- Adjustable Soft-start
- Adjustable Protection Delay
- Fault Status Indication
- Adjustable Operation Frequency from 100kHz to 1MHz
- Over Temperature Protection

### Applications

- LED Lighting
- LED TV
- LCD Display Modules







# **Pin Configuration**



Figure 2. Pin Configuration of AP3041 (Top View)



# **Pin Description**

Pin Number	Pin Name	Function
1	СТ	Capacitor setting shut down delay time
2	OV	Over output voltage protection pin
3	UVLO	Two resistors connected from this pin to GND and the power supply respectively are used to set start-up and shutdown level
4	EN	Enable pin
5	VIN	Input supply pin. This pin must be locally bypassed
6	VCC	This pin should be bypassed to GND with a ceramic capacitor
7	OUT	Connect this pin to the gate of external MOSFET, the gate driver has 1A peak current capability
8	GND	Ground
9	FAULT	This pin can be used to drive the external MOSFET. The logic of the driver signal is controlled by that of PWM pin and the signal phase of them is the same. This pin is pulled to ground under fault condition of OVP, UVLO, OTP, diode short circuit and LED short circuit.
10	RT	An external resistor connected from this pin to GND is used to set the operating frequency
11	CS	Sense switch current pin, which is used for current mode control and for current limit. The current limit voltage is 500mV
12	SC	Slope compensation for current sense. A resistor between SC and GND will program the slope compensation
13	SS/COMP	An external soft-start time capacitor is placed from this pin to GND and is charged by an internal 20µA current source to control regulator soft-start time. Compensation pin. This pin is the output of the internal error amplifier.
14	FB	Voltage feedback pin. The reference voltage is 500mV
15	PWM	This pin can be connected to current matched chip and receives error signal used to shut down the system
16	FLAG	Fault condition output pin. When the output is in short circuit condition, the FLAG outputs logic low to shut down the power path. Please refer to the application circuit



### **Functional Block Diagram**



Figure 3. Functional Block Diagram of AP3041



### **Ordering Information**



Package	Temperature Range	Part Number Marking ID		Packing Type	
SOIC-16	-40 to 85°C	AP3041M-G1	AP3041M-G1	Tube	
		AP3041MTR-G1	AP3041M-G1	Tape & Reel	

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.

## Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value	Unit
Input Voltage	V <sub>IN</sub>	30	V
VCC Pin Voltage	V <sub>CC</sub>	20	V
OUT Pin Voltage	V <sub>OUT</sub>	20	V
FAULT Pin Voltage	V <sub>FAULT</sub>	20	V
FB Pin Voltage	V <sub>FB</sub>	20	V
UVLO Pin Voltage	V <sub>UVLO</sub>	7	V
CS Pin Voltage	V <sub>CS</sub>	20	V
SC Pin Voltage	V <sub>SC</sub>	7	V
FLAG Pin Voltage	V <sub>FLAG</sub>	7	V
SS/COMP Pin Voltage	V <sub>SS/COMP</sub>	7	V
RT Pin Voltage	V <sub>RT</sub>	7	V
PWM Pin Voltage	$V_{PWM}$	7	V
EN Pin Voltage	V <sub>EN</sub>	30	V
OV Pin Voltage	V <sub>OV</sub>	7	V
Thermal Resistance (Junction to	0	82	°C/W
Ambient, No Heat Sink, Free Air)	$\theta_{\rm JA}$	82	C/ W



### Absolute Maximum Ratings (Note 1, Continued)

Parameter	Symbol	Value	Unit
Operating Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C
Lead Temperature (Soldering, 10 sec)	T <sub>LEAD</sub>	260	°C
ESD (Human Body Model)		2000	V
ESD (Machine Model)		200	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

# **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit	
Input Voltage	$V_{IN}$	5	27	V	
Operating Frequency	f	0.1	1	MHz	
Operating Temperature Range	$T_J$	-40	85	°C	

# **Electrical Characteristics**

V<sub>CC</sub>=12V, V<sub>EN</sub>=3.3V, T<sub>A</sub>=25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Voltage	V <sub>IN</sub>		5		27	V
Feedback Voltage	$V_{FB}$		490	500	510	mV
Supply Current	I <sub>CC</sub>	$V_{FB}=V_{IN}$ , no switching		1.5	5	mA
Shutdown Supply Current	IQ	V <sub>EN</sub> =0		1	2	μΑ
VCC Voltage	V <sub>CC</sub>	$11V \le V_{IN} \le 27V$	9.5	10.0	10.5	V
VCC voltage		$5V \le V_{IN} \le 10V, I_{CC} = 5mA$	V <sub>IN</sub> -0.5			V
VCC Current Limit	I <sub>CC-LIM</sub>			35		mA
VCC Pin UVLO Rising Threshold	V <sub>CC-HI</sub>			4.7		V
VCC Pin UVLO Falling Hysteresis	V <sub>CC-HYS</sub>			300		mV
Oscillator Frequency	f <sub>OSC</sub>		0.1		1	MHz
SC Peak Voltage	$V_{SC_{PK}}$		530		680	mV
UVLO Threshold	V <sub>UVLO</sub>		1.20	1.25	1.30	V
UVLO Hysteresis Current Source	I <sub>UVLO-HYS</sub>			10		μΑ



# **Electrical Characteristics (Continued)**

 $V_{CC}$ =12V,  $V_{EN}$ =3.3V,  $T_A$ =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Current Limit Threshold Voltage	V <sub>CS</sub>		0.48	0.5	0.52	V
RT Voltage	V <sub>RT</sub>		1.20	1.25	1.30	V
Error Amplifier Voltage Gain	G <sub>V</sub>			680		V/V
Error Amplifier Transconductance	Gs			500		μA/V
TNI D' The set of 1377 16	$V_{\rm EH}$		2.5			17
EN Pin Threshold Voltage	V <sub>EL</sub>				0.5	V
DWM Din Threshold Valtage	V <sub>IH</sub>		2.5			v
PWM Pin Threshold Voltage	V <sub>IL</sub>				0.5	v
OV Threshold	V <sub>OV</sub>			2.25		V
OV Hysteresis Current Source	I <sub>OV-HYS</sub>			10		μΑ
LED- Short to GND Detection Level	$V_{FB\_LOW}$			0.3		V
LED+ Short to LED-Detection Level	$V_{FB_HIGH}$			1.25		V
LED+ Short to GND Detection Level	V <sub>OV_LOW</sub>			0.3		V
Diode Short Detection Level	V <sub>CS_HIGH</sub>			1.75		V
CT Current Source	I <sub>CT</sub>			5		μΑ
CT Threshold Voltage	V <sub>CT</sub>			2.6		V
Maximum Duty Cycle	D <sub>MAX</sub>	f=200kHz	80	90		%
Soft-start Current Source	I <sub>SS</sub>		16	22	28	μΑ
OUT Pin Rising Time	t <sub>RISE</sub>	C <sub>OUT</sub> =1nF		20		
OUT Pin Falling Time	t <sub>FALL</sub>	C <sub>OUT</sub> =1nF		20		ns
OUT High Voltage Level (V <sub>CC</sub> -V <sub>OUT</sub> )	V <sub>OUT-H</sub>	I <sub>OUT</sub> =50mA		0.25	0.75	V
OUT Low Voltage Level (V <sub>OUT</sub> )	V <sub>OUT-L</sub>	I <sub>OUT</sub> =50mA		0.25	0.75	V
FAULT Pin Rising Time	t <sub>RISE</sub>	C <sub>FAULT</sub> =1nF		100		
FAULT Pin Falling Time	t <sub>FALL</sub>	C <sub>FAULT</sub> =1nF		100		ns
FAULT High Voltage Level (V <sub>CC</sub> -V <sub>FAULT</sub> )	V <sub>FAULT_H</sub>	I <sub>FAULT</sub> =10mA		0.25	0.75	V
FAULT Low Voltage Level	V <sub>FAULT_L</sub>	I <sub>FAULT</sub> =10mA		0.25	0.75	V
FAULT Minimum Pulse Width	t <sub>D</sub>	Oscillator Frequency=200kHz		20		μs
FLAG High Voltage Level	V <sub>FLAG-H</sub>	I <sub>FLAG</sub> =500µA		2		V
FLAG Low Voltage Level	V <sub>FLAG-L</sub>	I <sub>FLAG</sub> =500µA		0.25	0.75	V
Thermal Shutdown Temperature	T <sub>OTSD</sub>			160		°C
Thermal Shutdown Hysteresis	T <sub>HYS</sub>			20		°C



V<sub>IN</sub>=12V

Boost Controller for WLED Driver in Medium-sized LCD Panel AP3041

Frequency (kHz)

# **Typical Performance Characteristics**



Figure 4. LED Current vs. PWM Duty

Figure 5. Frequency vs.  $R_T$ 

 $\mathsf{R}_{_{\mathsf{T}}}$  (k $\Omega$ )



Figure 6.  $V_{\text{FB}}$  vs. Temperature

Figure 7. Supply Current vs. Temperature



R<sub>-</sub>=82k

100

125

150

Boost Controller for WLED Driver in Medium-sized LCD Panel AP3041

400

380

360

340

320

300

-75

-50 -25

Frequency (kHz)

# **Typical Performance Characteristics (Continued)**



Figure 8. Supply Current vs. Temperature

Figure 9. Frequency vs. Temperature

25

Temperature (°C)

0

50

75



Figure 10.  $V_{CC}$  vs. Input Voltage



Figure 11. CS Threshold vs. Temperature



2.0

**Typical Performance Characteristics (Continued)** 



1.8 Rising - · - Falling 1.0 -50 25 -75 -25 50 100 125 150 0 75 Temperature (<sup>o</sup>C)

Figure 12. EN Threshold Voltage vs. Temperature

Figure 13. PWM Threshold Voltage vs. Temperature



Figure 14. OV Threshold Voltage vs. Temperature

0.36 0.34 0.32 0.32 0.32 0.30 0.28 0.28 0.25 0.30 0.28 0.26 0.32 0.30 0.28 0.26 0.32 0.30 0.28 0.26 0.32 0.30 0.28 0.26 0.32 0.30 0.28 0.26 0.32 0.25 0.30 0.25 0.32 0.30 0.25 0.32 0.30 0.25 0.32 0.30 0.25 0.32 0.30 0.25 

Figure 15. FB Low Threshold Voltage vs. Temperature

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## **Typical Performance Characteristics (Continued)**



Figure 16. FB High Threshold Voltage vs. Temperature



Figure 17. OV Low Threshold Voltage vs. Temperature



Figure 18. Soft-start Current vs. Temperature



Figure 19.CT Charge Current vs. Temperature



# **Typical Application**



Figure 20. Typical Application Circuit of AP3041



#### **Mechanical Dimensions**

SOIC-16

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.

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#### **BCD Semiconductor Manufacturing Limited**

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